BCP55; BCX55; BC55PA

60 V, 1 A NPN medium power transistors Rev. 8 — 24 October 2011

Product data sheet

1. **Product profile**

1.1 General description

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

Product overview Table 1.

Type number[1]	Package		PNP complement	
	NXP	JEITA	JEDEC	
BCP55	SOT223	SC-73	-	BCP52
BCX55	SOT89	SC-62	TO-243	BCX52
BC55PA	SOT1061	-	-	BC52PA

^[1] Valid for all available selection groups.

1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 qualified

1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	60	V
I _C	collector current		-	-	1	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1$ ms	-	-	2	Α
h _{FE}	DC current gain	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	[<u>1]</u> 63	-	250	
	h _{FE} selection -10	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	[<u>1]</u> 63	-	160	
	h _{FE} selection -16	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	[<u>1]</u> 100	-	250	

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta = 0.02$.



2. Pinning information

Table 3. **Pinning** Simplified outline **Graphic symbol** Pin Description **SOT223** 1 base 2, 4 2 collector 3 emitter 4 collector sym016 **SOT89** 1 emitter 2 collector 3 base SOT1061 1 base] 3 | emitter collector 3 sym021 Transparent top view

3. Ordering information

Table 4. Ordering information

Type number[1]	Package						
	Name	Description	Version				
BCP55	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				
BCX55	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89				
BC55PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 2 \times 2 \times 0.65 mm	SOT1061				

^[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes

3	
Type number	Marking code
BCP55	BCP55
BCP55-10	BCP55/10
BCP55-16	BCP55/16
BCX55	BE
BCX55-10	BG
BCX55-16	BM
BC55PA	AW
BC55-10PA	ВН
BC55-16PA	ВЈ

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	60	V
V_{CEO}	collector-emitter voltage	open base	-	60	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
Ic	collector current		-	1	Α
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	2	Α
I _B	base current		-	0.3	Α
I _{BM}	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	0.3	Α
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	BCP55		<u>[1]</u> _	0.65	W
			[2] _	1.00	W
			[3]	1.35	W
	BCX55		<u>[1]</u> _	0.50	W
			[2] _	0.95	W
			[3]	1.35	W
	BC55PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			[4]	0.81	W
			<u>[5]</u> _	1.65	W
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

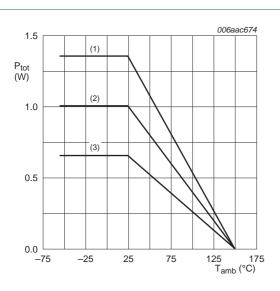
^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

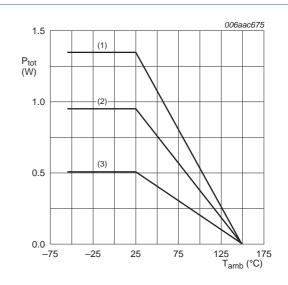
^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



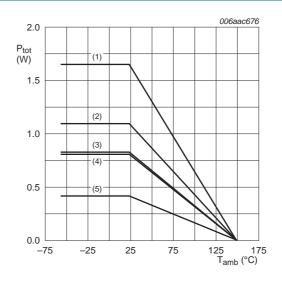
- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 1. Power derating curves SOT223



- (1) FR4 PCB, mounting pad for collector 6 cm²
- (2) FR4 PCB, mounting pad for collector 1 cm²
- (3) FR4 PCB, standard footprint

Fig 2. Power derating curves SOT89



- (1) FR4 PCB, 4-layer copper, mounting pad for collector 1 cm²
- (2) FR4 PCB, single-sided copper, mounting pad for collector 6 cm²
- (3) FR4 PCB, single-sided copper, mounting pad for collector 1 cm²
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 3. Power derating curves SOT1061

6. Thermal characteristics

Table 7. Thermal characteristics

able 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	BCP55		<u>[1]</u> _	-	192	K/W
			[2] _	-	125	K/W
			[3] _	-	93	K/W
	BCX55		<u>[1]</u> _	-	250	K/W
			[2] _	-	132	K/W
			[3] _	-	93	K/W
	BC55PA		<u>[1]</u> _	-	298	K/W
			[2] _	-	151	K/W
			[3] _	-	114	K/W
			[4] _	-	154	K/W
			[5] _	-	76	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point					
	BCP55		-	-	16	K/W
	BCX55		-	-	16	K/W
	BC55PA		-	-	20	K/W

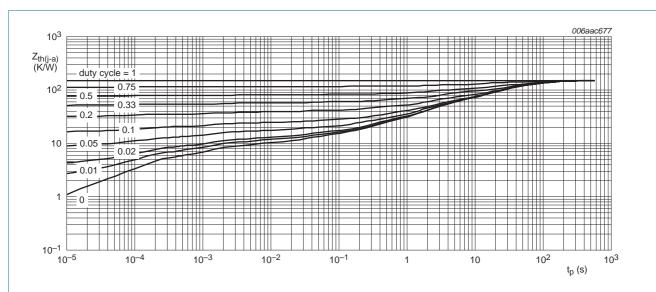
^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm².

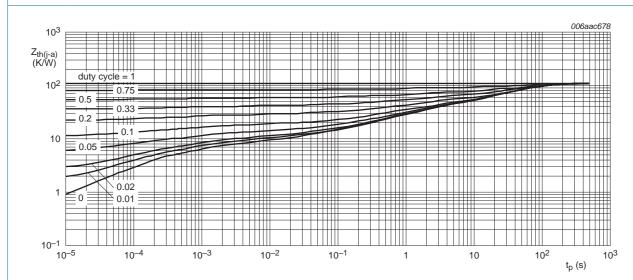
^[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

^[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



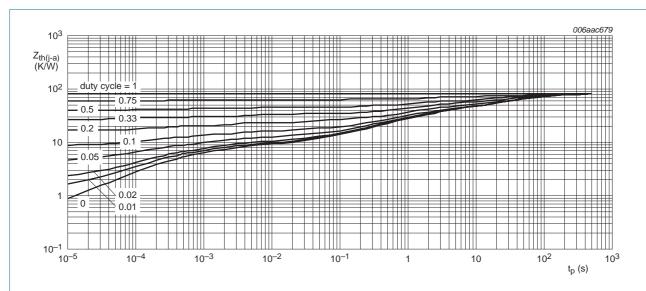
FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



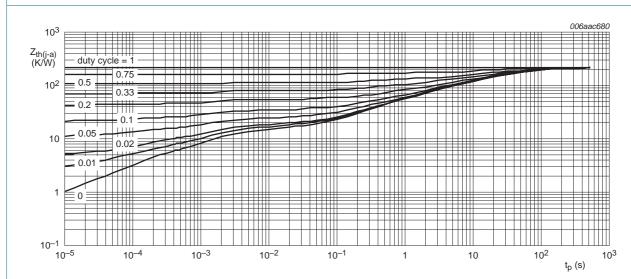
FR4 PCB, mounting pad for collector 1 cm²

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, mounting pad for collector 6 cm²

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT223; typical values



FR4 PCB, standard footprint

Fig 7. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

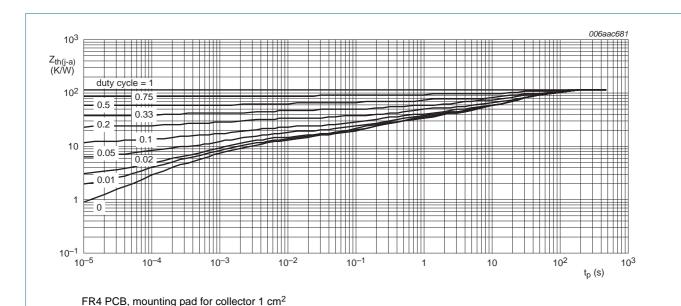
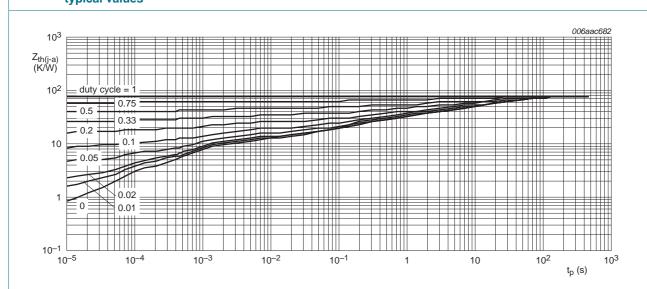


Fig 8. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values



FR4 PCB, mounting pad for collector 6 cm²

Fig 9. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT89; typical values

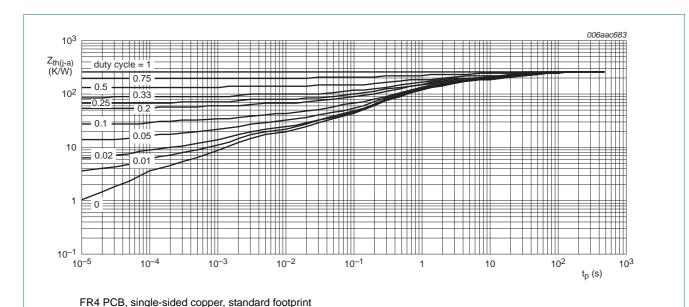


Fig 10. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

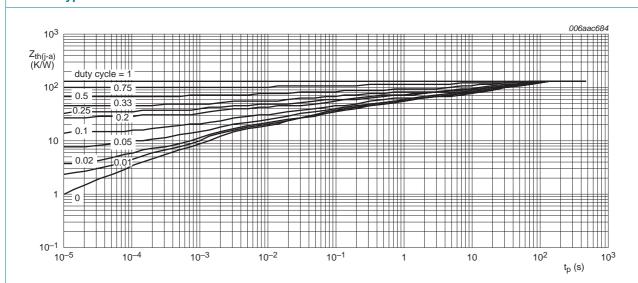
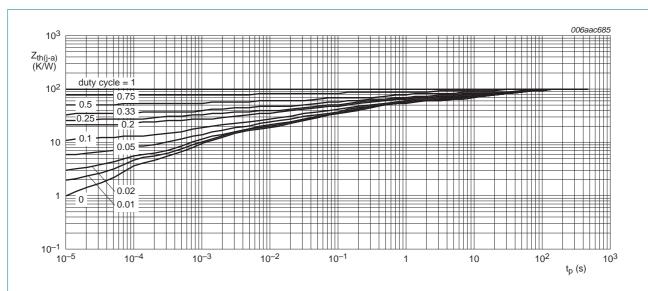


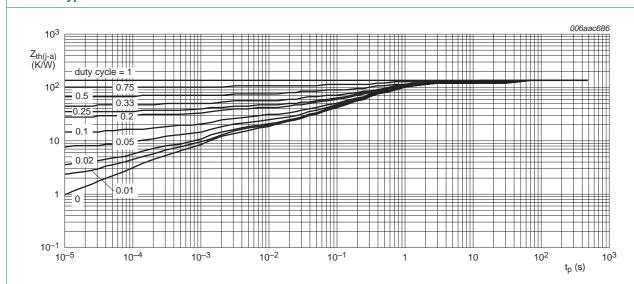
Fig 11. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

FR4 PCB, single-sided copper, mounting pad for collector 1 cm²



FR4 PCB, single-sided copper, mounting pad for collector 6 cm²

Fig 12. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values



FR4 PCB, 4-layer copper, standard footprint

Fig 13. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

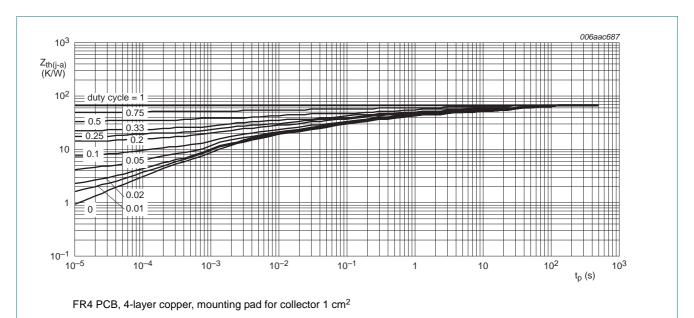


Fig 14. Transient thermal impedance from junction to ambient as a function of pulse duration for SOT1061; typical values

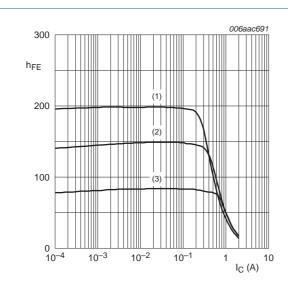
7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I_{CBO}	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}$		-	-	100	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 2 V					
		$I_C = 5 \text{ mA}$	<u>[1]</u>	63	-	-	
		$I_C = 150 \text{ mA}$	<u>[1]</u>	63	-	250	
		$I_C = 500 \text{ mA}$	<u>[1]</u>	40	-	-	
	DC current gain	V _{CE} = 2 V					
	h _{FE} selection -10	$I_C = 150 \text{ mA}$	<u>[1]</u>	63	-	160	
	h _{FE} selection -16	$I_C = 150 \text{ mA}$	[1]	100	-	250	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	[1]	-	-	0.5	V
V_{BE}	base-emitter voltage	$V_{CE} = 2 \text{ V}; I_{C} = 500 \text{ mA}$	<u>[1]</u>	-	-	1	V
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	6	-	pF
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA};$ f = 100 MHz		100	180	-	MHz

^[1] Pulse test: $t_p \le 300~\mu s;~\delta = 0.02.$



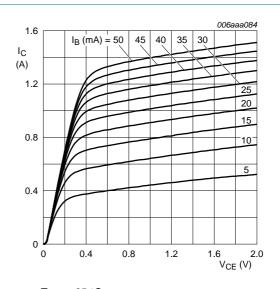
 $V_{CE} = 2 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

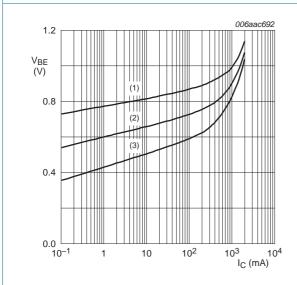
(3) $T_{amb} = -55 \, ^{\circ}C$

Fig 15. DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig 16. Collector current as a function of collector-emitter voltage; typical values



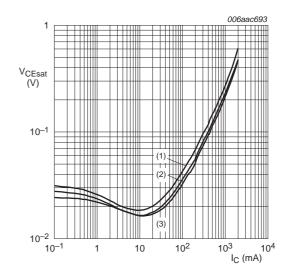
 $V_{CE} = 2 V$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = 100 \, ^{\circ}C$

Fig 17. Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B} = 10$

(1) $T_{amb} = 100 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55 \, ^{\circ}C$

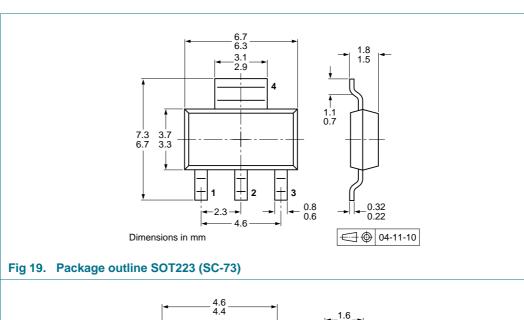
Fig 18. Collector-emitter saturation voltage as a function of collector current; typical values

8. Test information

8.1 Quality information

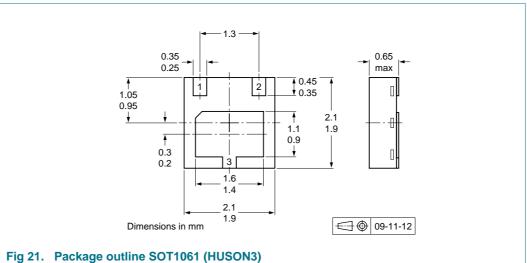
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



2.6 2.4 1.8 1.4 2.6 2.4 1.2 0.8 1.2 0.8 0.40 1.5 3.75 0.48 0.23 Dimensions in mm

Fig 20. Package outline SOT89 (SC-62/TO-243)



10. Packing information

Packing methods Table 9.

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package	•		Packing quantity		
number[2]				1000	3000	4000
BCP55	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BCX55	SOT89	8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC55PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

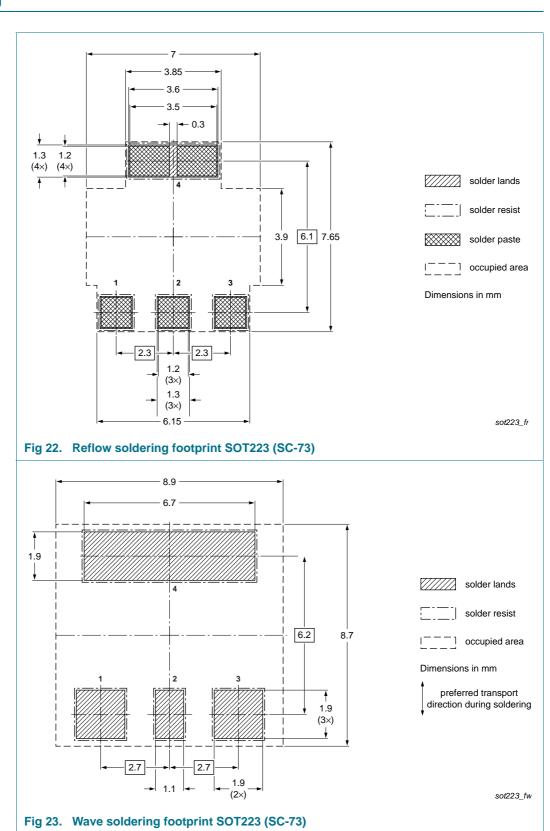
^[1] For further information and the availability of packing methods, see Section 14.

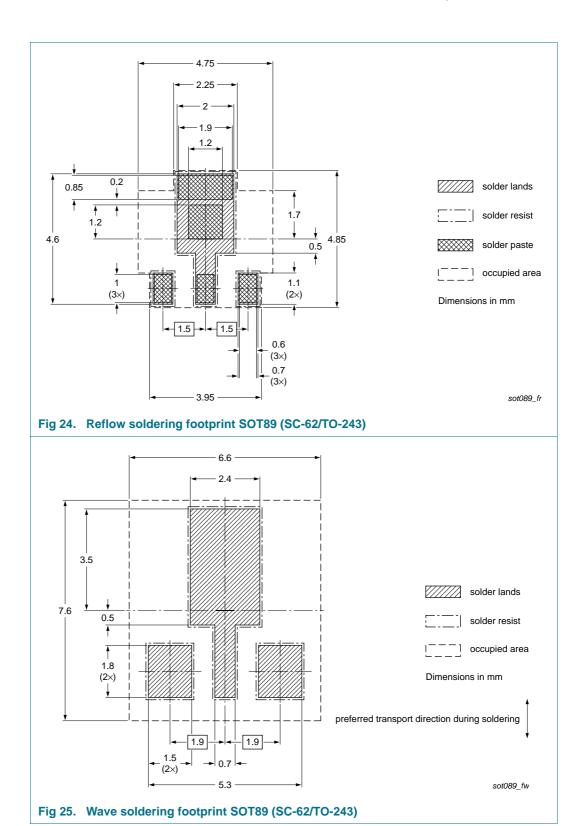
Valid for all available selection groups.

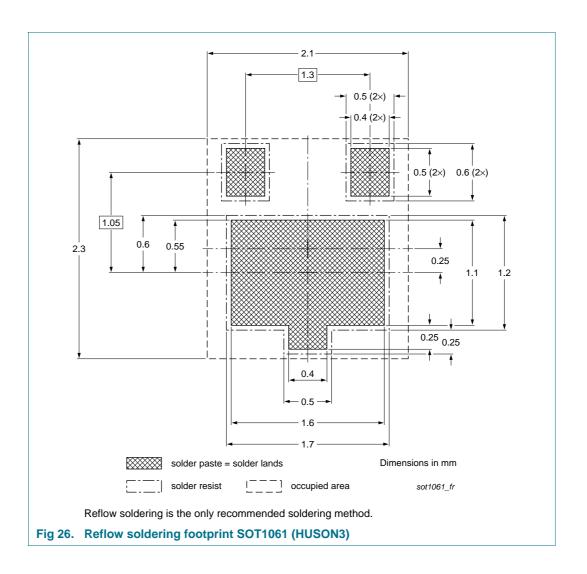
T1: normal taping

^[4] T3: 90° rotated taping

11. Soldering







12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BCP55_BCX55_BC55PA v.8	20111024	Product data sheet	-	BC637_BCP55_BCX55 v.7		
Modifications:	 Type number 	er removed: BC637				
	 Type number 	er added: BC55PA, BC55-	10PA and BC55-1	6PA		
	 Section 1 "F 	Product profile": updated				
	 Section 2 "F 	Pinning information": updat	ed			
	• Table 6 and	7: updated according to la	atest measuremen	ts		
	• Figure 1, 2,	4, 5, 7 to 9, 15, 17 and 18	: updated			
	 Figure 3, 6, 10 to 14: added 					
	 Section 8 "T 	est information": added				
	 Section 10 ' 	'Packing information": upd	ated			
	Section 11 "	'Soldering": added				
	 Section 13 ' 	'Legal information": update	ed			
BC637_BCP55_BCX55 v.7	20070625	Product data sheet	-	BC637_BCP55_BCX55 v.6		
BC637_BCP55_BCX55 v.6	20050218	Product data sheet	CPCN2004050	BC635_637_639 v.4		
			29	BCP54_55_56 v.5		
				BCX54_55_56 v.4		
BC635_637_639 v.4	20011010	Product specification	-	BC635_637_639 v.3		
BCP54_55_56 v.5	20030206	Product specification	-	BCP54_55_56 v.4		
BCX54_55_56 v.4	20011010	Product specification	-	BCX54_55_56 v.3		

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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BCP55_BCX55_BC55PA

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BCP55; BCX55; BC55PA

60 V, 1 A NPN medium power transistors

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

15. Contents

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

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NTE195A NTE92 2N4401-A 2N6728 2SA1419T-TD-H 2SA2126-E 2SB1204S-TL-E 2SC2712S-GR,LF 2SC4731T-AY FJPF5304DTU

2N2369ADCSM 2N2907A 2N3904-NS 2N5769 2SB1324-TD-E 2SC2412KT146S 2SC3332T 2SC3902S 2SC5231C8-TL-E 2SD1685F

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